

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: tba
Examiner: tba

In Re PATENT APPLICATION OF

Applicant(s):	Alexandre ELLISON et al.)	
)	
Appl. No.:	10/526,259)	INFORMATION
)	DISCLOSURE
Filing Date:	February 28, 2005)	<u>STATEMENT</u>
)	
For:	LIGHTLY DOPED SILICON CARBIDE WAFER AND USE THEREOF IN HIGH POWER DEVICES)	26694
)	U.S. PATENT AND
)	TRADEMARK OFFICE
)	
Atty. Dkt.:	35947-213490)	

October 13, 2005

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

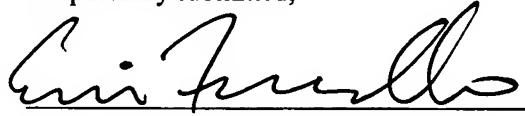
Sir:

This is an Information Disclosure Statement submitted under 37 C.F.R. § 1.97 within the time specified under 37 C.F.R. § 1.97(b).

Enclosed is a PTO-1449, and copies of references cited therein.

This Information Disclosure Statement is being filed before the mailing date of a first Office Action on the merits.

Respectfully submitted,



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Date: 10/13/05

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Rec'd PCT/PTO 13 OCT 2005

PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE

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Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

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of

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Complete if Known

Application Number	10/526,059
Filing Date	February 28, 2005
First Named Inventor	Alexandre ELLISON et al.
Group Art Unit	tba
Examiner Name	tba

Attorney Docket Number

35947-213490

U.S. PATENT DOCUMENTS

Examiner Initials *	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ₆
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OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS

Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	1	J.R. JENNY, M. SKOWRONSKI, W.C. MITCHEL, H.M. HOBGOOD, R.C. GLASS, G. AUGUSTINE and R.H. HOPKINS; Optical and electrical characterization of boron impurities in silicon carbide grown by physical vapor transport; J. Appl. Phys. 79 (5), March 1996; pps. 2326-2331.	
	2	M. TRIVEDI, S. PENDHARKAR and K. SHENAI; High Temperature Performance Limits of IGBT Modules; 1998 IEEE; pps. 977-981.	
	3	AKIRA ITOH and HIROYUKI MATSUNAMI; Single Crystal Growth of SiC and Electronic Devices; Critical Reviews in Solid State and Materials Sciences; 1997; 22(2); pps. 111-197; CRC Press LLC.	

Examiner Signature

Date Considered

¹ EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

² Unique citation designation number. ³ See attached Kinds of U.S. Patent Documents. ⁴ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁵ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁶ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁷ Applicant is to place a check mark here if English language Translation is attached.

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